

Revision 0.90

# SINGLE FREQUENCY LASER DIODES Distributed Feedback Laser



### General Product Information

Product	Application
852 nm DFB Laser	Spectroscopy (Cs D2 line)
with hermetic 14 Pin-Butterfly Housing (RoHS compliant)	Metrology
including Monitor Diode, Thermoelectric Cooler and Thermistor	Atomic Clock
with integrated Beam Collimation	



## **Absolute Maximum Ratings**

Parameter	Symbol	Unit	min	typ	max
Storage Temperature	$T_S$	°C	-40		85
Operational Temperature at Case	$T_{C}$	°C	-40		85
Operational Temperature at Laser Chip	$T_{LD}$	°C	10		50
Forward Current	I <sub>F</sub>	mA			200
Reverse Voltage	$V_R$	V			2
Output Power	$P_{opt}$	mW			110
TEC Current	I <sub>TEC</sub>	Α			1.1
TEC Voltage	$V_{TEC}$	V			2.8

### Measurement Conditions / Comments

Stress in excess of one of the Absolute Maximum Ratings may damage the laser. Please note that a damaging optical power level may occur although the maximum current is not reached. These are stress ratings only, and functional operation at these or any other conditions beyond those indicated under Recommended Operational Conditions is not implied.

### **Recommended Operational Conditions**

Parameter	Symbol	Unit	min	typ	max
Operational Temperature at Case	$T_{\rm case}$	°C	-20		65
Operational Temperature at Laser Chip	$T_{LD}$	°C	15		45
Forward Current	I <sub>F</sub>	mA			180
Output Power	P <sub>opt</sub>	mW	20		100

Measurement Conditions / Comments
measured by integrated Thermistor

## Characteristics at $T_{LD} = 25^{\circ}$ at BOL

Parameter	Symbol	Unit	min	typ	max
Center Wavelength	$\lambda_{C}$	nm	851	852	853
Target Wavelength	$\lambda_{\text{T}}$	nm		852.347	
Linewidth (FWHM)	Δλ	MHz		0.6	1
Mode-hop free Tuning Range	$\Delta \lambda_{\text{tune}}$	pm	25		
Sidemode Supression Ratio	SMSR	dB	30	50	
Temperature Coefficient of Wavelength	dλ / dT	nm / K		0.06	
Current Coefficient of Wavelength	dλ / dl	nm / mA		0.003	

Measurement Conditions / Comments
see images on page 4

reached within  $T_{LD}$  = 15 ° ... 45° C at 100 mW > 10 GHz, at target wavelength  $P_{opt}$  = 100 mW

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Characteristics at T <sub>LD</sub> = 25° at BOL					
Symbol	Unit	min	typ	max	
I <sub>LD</sub>	mA			180	
η	W/A	0.6	0.8	1.0	
$I_{th}$	mA			70	
$\Theta_{  }$	0		0.1		
$\Theta_{\perp}$	0		0.1		
d	mm		1.0	1.2	
$d_{\bot}$	mm		0.8	1.2	
DOP	%		90		
	$\begin{array}{c} \text{Symbol} \\ \\ I_{\text{LD}} \\ \\ \eta \\ \\ I_{\text{th}} \\ \\ \Theta_{  } \\ \\ \Theta_{\perp} \\ \\ d_{  } \\ \\ d_{\perp} \end{array}$	$ \begin{array}{c c} \text{Symbol} & \text{Unit} \\ \hline \\ I_{\text{LD}} & \text{mA} \\ \hline \\ \eta & \text{W / A} \\ \hline \\ I_{\text{th}} & \text{mA} \\ \hline \\ \Theta_{  } & \circ \\ \hline \\ \Theta_{\perp} & \circ \\ \hline \\ d_{  } & \text{mm} \\ \hline \\ d_{\perp} & \text{mm} \\ \end{array} $	$\begin{array}{c cccc} \text{Symbol} & \text{Unit} & \text{min} \\ & & & & \\ & & & & \\ & & & & \\ & & & & \\ & & & & \\ & & & & \\ & & & & \\ & & & & \\ & & & & \\ & & & \\ & & & \\ & & & \\ & & & \\ & & & \\ & & & \\ & & & \\ & & & \\ & & & \\ & & & \\ & & & \\ & & & \\ & & & \\ & & & \\ & & & \\ & & \\ & & & \\ & & \\ & & & \\ &$	$\begin{tabular}{ c c c c c c c c c c c c c c c c c c c$	

parallel to the base plate of the housing (see p. 3)
perpendicular to base plate of the housing (see p. 3)
parallel to the base plate of the housing (see p. 3)
perpendicular to base plate of the housing (see p. 3)
$P_{\rm opt} = 100$ mW; E field parallel to the base plate

**Measurement Conditions / Comments** 

Symbol	Unit	min	typ	max
I <sub>mon</sub> / P <sub>opt</sub>	μA/mW	0.5		10
	-, -	Symbol Unit I <sub>mon</sub> / P <sub>opt</sub> µA/mW	.,	., ., ., ., ., ., ., ., ., ., ., ., ., .

Meas	urement Conditions / Comments
$J_R =$	5 V

I nermoelectric Cooler					
Parameter	Symbol	Unit	min	typ	max
Current	I <sub>TEC</sub>	А		0.4	
Voltage	$U_TEC$	V		1.3	
Power Dissipation (total loss at case)	P <sub>loss</sub>	W		0.4	
Temperature Difference	ΔΤ	K			50

Measurement Conditions / Comments
$P_{opt} = 100 \text{ mW}, \Delta T = 20 \text{ K}$
$P_{opt} = 100 \text{ mW}, \Delta T = 20 \text{ K}$
$P_{opt} = 100 \text{ mW}, \Delta T = 20 \text{ K}$
$P_{opt} = 100 \text{ mW, } \Delta T =  T \text{case - TLD} $
$P_{opt} = 100 \text{ mW}, \Delta T =  T \text{case} - T \text{LD} $

Parameter	Symbol	Unit	min	typ	max
Resistance	R	kΩ		10	
Beta Coefficient	β			3892	
Steinhart & Hart Coefficient A	А			1.1293 x 10	-3
Steinhart & Hart Coefficient B	В			2.3410 x 10	-4
Steinhart & Hart Coefficient C	C		;	3.7755 x 10	-8

Thermistor (Standard NTC Type)

Measurement Conditions / Comments			
$T_{LD} = 25^{\circ} C$			
$R_1  /  R_2 = e^{ \beta  (1/T_1  -  1/T_2)} $ at $T_{LD} =$	0° 50° C		
$1/T = A + B(\ln R) + C(\ln R)^3$			
T: temperature in Kelvin			
R: resistance at T in Ohm			



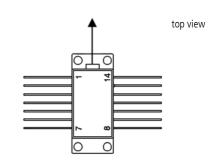
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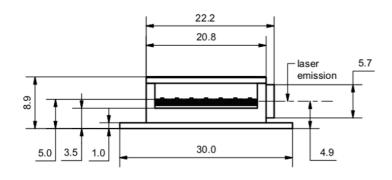


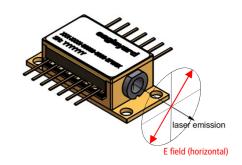
A:-		
Assig	ınm	ent

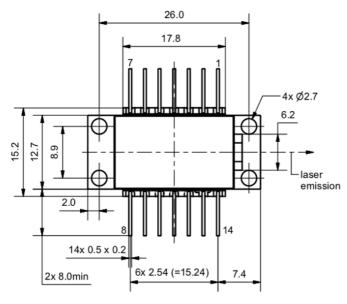
1	Thermoelectric Cooler (+)	14	Thermoelectric Cooler (-)		
2	Thermistor	13	Case		
3	Photodiode (Anode)	12	not connected		
4	Photodiode (Cathode)	11	Laser Diode (Cathode)		
5	Thermistor	10	Laser Diode (Anode)		
6	not connected	9	not connected		
7	not connected	8	not connected		
All 14 pins are isolated from case.					



## Package Drawings







AIZ-15-0729-0947





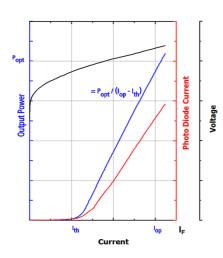
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## SINGLE FREQUENCY LASER DIODES **Distributed Feedback Laser**

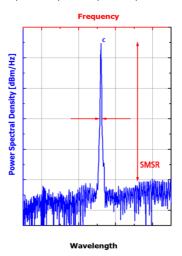


### Typical Measurement Results

Output Power vs. Current



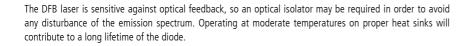
Spectra at Specified Optical Output Power



Performance figures, data and any illustrative material provided in this specification are typical and must be specifically confirmed in writing by eagleyard Photonics before they become applicable to any particular order or contract. In accordance with the eagleyard Photonics policy of continuous improvement specifications may change without notice.

#### Unpacking, Installation and Laser Safety

Unpacking the laser diodes should only be done at electrostatic safe workstations (EPA). Though protection against electro static discharge (ESD) is implemented in the laser package, charges may occur at surfaces. Please store this product in its original package at a dry, clean place until final use. During device installation, ESD protection has to be maintained.



Avoid direct and/or indirect exposure to the free running beam. Collimating and focussing the free running beam with optics as common in optical instruments will increase threat to the human eye.

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